## NSN 5962-01-363-6392

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Burn in and bipolar and hermetically sealed and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
12 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Memory Device Type:
Memory Device Type: Prom
Prom
Prom Terminal Type And Quantity:
Prom  Terminal Type And Quantity:  18 printed circuit
Prom Terminal Type And Quantity: 18 printed circuit Shelf Life:
Prom  Terminal Type And Quantity:  18 printed circuit  Shelf Life:  N/a
Prom Terminal Type And Quantity: 18 printed circuit Shelf Life: N/a Unit Of Measure:
Prom Terminal Type And Quantity:  18 printed circuit Shelf Life: N/a Unit Of Measure:
Prom Terminal Type And Quantity: 18 printed circuit Shelf Life: N/a Unit Of Measure: Demilitarization:
Prom  Terminal Type And Quantity:  18 printed circuit  Shelf Life: N/a  Unit Of Measure:  Demilitarization: Yes - demil/mli
Prom  Terminal Type And Quantity:  18 printed circuit  Shelf Life:  N/a  Unit Of Measure:   Demilitarization:  Yes - demil/mli  Fiig:
Prom  Terminal Type And Quantity:  18 printed circuit  Shelf Life:  N/a  Unit Of Measure:   Demilitarization:  Yes - demil/mli  Fiig: